Operational Amplifiers, Single Supply, Quad

The LM324 series are low-cost, quad operational amplifiers with true differential inputs. They have several distinct advantages over standard operational amplifier types in single supply applications. The quad amplifier can operate at supply voltages as low as 3.0 V or as high as 32 V with quiescent currents about one-fifth of those associated with the MC1741 (on a per amplifier basis). The common mode input range includes the negative supply, thereby eliminating the necessity for external biasing components in many applications. The output voltage range also includes the negative power supply voltage.

Features

- Short Circuited Protected Outputs
- True Differential Input Stage
- Single Supply Operation: 3.0 V to 32 V
- Low Input Bias Currents: 100 nA Maximum (LM324A)
- Four Amplifiers Per Package
- Internally Compensated
- Common Mode Range Extends to Negative Supply
- Industry Standard Pinouts
- ESD Clamps on the Inputs Increase Ruggedness without Affecting Device Operation
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant



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PDIP-14 N SUFFIX CASE 646

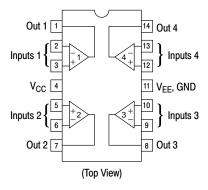


SOIC-14 D SUFFIX CASE 751A



TSSOP-14 DTB SUFFIX CASE 948G

PIN CONNECTIONS



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 10 of this data sheet.

DEVICE MARKING INFORMATION

See general marking information in the device marking section on page 11 of this data sheet.

MAXIMUM RATINGS ($T_A = +25^{\circ}C$, unless otherwise noted.)

Rating		Symbol	Value	Unit
Power Supply Voltages Single Supply Split Supplies		V _{CC} V _{CC} , V _{EE}	32 ±16	Vdc
Input Differential Voltage Range (Note 1)		V_{IDR}	±32	Vdc
Input Common Mode Voltage Range		V _{ICR}	-0.3 to 32	Vdc
Output Short Circuit Duration		t _{SC}	Continuous	
Junction Temperature		TJ	150	°C
Thermal Resistance, Junction-to-Air (Note 2)	Case 646 Case 751A Case 948G	$R_{ hetaJA}$	118 156 190	°C/W
Storage Temperature Range		T _{stg}	-65 to +150	°C
	LM224 , LM324A, LM324E LM2902, LM2902E	T _A	-25 to +85 0 to +70 -40 to +105	°C
LM2902V,	NCV2902 (Note 3)		-40 to +125	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

ESD RATINGS

Rating	НВМ	ММ	Unit
ESD Protection at any Pin (Human Body Model – HBM, Machine Model – MM)			
NCV2902 (Note 3)	2000	200	V
LM324E, LM2902E	2000	200	V
LM324DG/DR2G, LM2902DG/DR2G	200	100	V
All Other Devices	2000	200	V

^{1.} Split Power Supplies.

^{2.} All R_{θJA} measurements made on evaluation board with 1 oz. copper traces of minimum pad size. All device outputs were active.

^{3.} NCV2902 is qualified for automitive use.

ELECTRICAL CHARACTERISTICS ($V_{CC} = 5.0 \text{ V}$, $V_{EE} = GND$, $T_A = 25^{\circ}C$, unless otherwise noted.)

			LM224			LM324	4	LM	324, LM	324E	LM2	902, LM	2902E	LM29	02V/NC	V2902	
Characteristics	Symbol	Min	Тур	Max	Min	Тур	Max	Unit									
Input Offset Voltage V _{CC} = 5.0 V to 30 V V _{ICR} = 0 V to	V _{IO}																mV
V_{CC} -1.7 V, V_{O} = 1.4 V, R_{S} = 0 Ω T_{A} = 25°C		_	2.0	5.0	_	2.0	3.0	_	2.0	7.0	_	2.0	7.0	_	2.0	7.0	
$T_A = T_{high}$ (Note 4) $T_A = T_{low}$ (Note 4)		-	- -	7.0 7.0	-	- -	5.0 5.0	-	_ _	9.0 9.0	-	- -	10 10	-	- -	13 10	
Average Temperature Coefficient of Input Offset Voltage	$\Delta V_{IO}/\Delta T$	-	7.0	_	-	7.0	30	-	7.0	-	-	7.0	-	-	7.0	_	μV/°C
$T_A = T_{high}$ to T_{low} (Notes 4 and 6)																	
Input Offset Current $T_A = T_{high}$ to T_{low} (Note 4)	I _{IO}	-	3.0	30 100	-	5.0 –	30 75	-	5.0 –	50 150	-	5.0 –	50 200	-	5.0 –	50 200	nA
Average Temperature Coefficient of Input Offset Current	$\Delta I_{IO}/\Delta T$	_	10	_	_	10	300	_	10	-	-	10	-	_	10	_	pA/°C
$T_A = T_{high}$ to T_{low} (Notes 4 and 6)																	
Input Bias Current $T_A = T_{high}$ to T_{low} (Note 4)	I _{IB}	-	-90 -	-150 -300	-	-45 -	-100 -200	-	-90 -	-250 -500	-	-90 -	-250 -500	-	-90 -	-250 -500	nA
Input Common Mode Voltage Range (Note 5)	V _{ICR}																V
$V_{CC} = 30 \text{ V}$		0	_	28.3	0	_	28.3	0	_	20.2	0	_	28.3	0	_	28.3	
$T_A = +25$ °C $T_A = T_{high}$ to T_{low} (Note 4)		0	-	28	0	_	28	0	-	28.3 28	0	-	28	0	-	28	
Differential Input Voltage Range	V_{IDR}	_	-	V _{CC}	_	-	V _{CC}	_	-	V _{CC}	-	-	V _{CC}	-	-	V _{CC}	٧
Large Signal Open Loop Voltage Gain $R_1 = 2.0 \text{ k}\Omega$,	A _{VOL}	50	100	_	25	100	_	25	100	_	25	100	_	25	100	_	V/mV
$V_{CC} = 15 \text{ V},$ for Large V_O Swing																	
$T_A = T_{high}$ to T_{low} (Note 4)		25	ı	_	15	_	_	15	_	_	15	ı	_	15	ı	_	
Channel Separation 10 kHz \leq f \leq 20 kHz, Input Referenced	CS	-	-120	-	-	-120	-	-	-120	-	-	-120	-	-	-120	-	dB
Common Mode Rejection, $R_S \le 10 \text{ k}\Omega$	CMR	70	85	_	65	70	-	65	70	-	50	70	-	50	70	_	dB
Power Supply Rejection	PSR	65	100	-	65	100	-	65	100	_	50	100	-	50	100	-	dB

4. LM224: T_{low} = -25°C, T_{high} = +85°C LM324/LM324A/LM324E: T_{low} = 0°C, T_{high} = +70°C LM2902/LM2902E: T_{low} = -40°C, T_{high} = +105°C LM2902V & NCV2902: T_{low} = -40°C, T_{high} = +125°C NCV2902 is qualified for automotive use.

6. Guaranteed by design.

The input common mode voltage or either input signal voltage should not be allowed to go negative by more than 0.3 V. The upper end of the common mode voltage range is V_{CC} –1.7 V, but either or both inputs can go to +32 V without damage, independent of the magnitude of V_{CC}.

ELECTRICAL CHARACTERISTICS (V_{CC} = 5.0 V, V_{EE} = GND, T_A = 25°C, unless otherwise noted.)

			LM224			LM324	4	LM:	324, LM	324E	LM29	902, LM	2902E	LM29	02V/NC	V2902	
Characteristics	Symbol	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
Output Voltage – High Limit $V_{CC} = 5.0 \text{ V}, R_L = 2.0 \text{ k}\Omega, T_A = 25^{\circ}\text{C}$ $V_{CC} = 30 \text{ V}$ $R_L = 2.0 \text{ k}\Omega$ $(T_A = T_{high to} T_{low})$ $(Note 7)$ $V_{CC} = 30 \text{ V}$ $R_L = 10 \text{ k}\Omega$ $(T_A = T_{high to} T_{low})$	VoH	3.3 26 27	3.5	-	3.3 26 27	3.5	-	3.3 26 27	3.5	-	3.3 26 27	3.5	-	3.3 26 27	3.5	-	V
(Note 7) Output Voltage – Low Limit, $V_{CC} = 5.0 \text{ V}$, $R_L = 10 \text{ k}\Omega$, $T_A = T_{high} \text{ to } T_{low}$ (Note 7)	V _{OL}	-	5.0	20	-	5.0	20	-	5.0	20	-	5.0	100	-	5.0	100	mV
Output Source Current $(V_{ID} = +1.0 \text{ V}, V_{CC} = 15 \text{ V})$ $T_A = 25^{\circ}\text{C}$ $T_A = T_{high} \text{ to } T_{low}$ (Note 7)	I _{O+}	20 10	40 20	-	20 10	40 20	-	20 10	40 20	- -	20 10	40 20	-	20 10	40 20	-	mA
Output Sink Current $(V_{ID} = -1.0 \text{ V}, \\ V_{CC} = 15 \text{ V})$ $T_A = 25^{\circ}\text{C}$ $T_A = T_{high} \text{ to } T_{low}$ (Note 7) $(V_{ID} = -1.0 \text{ V}, \\ V_O = 200 \text{ mV}, \\ T_A = 25^{\circ}\text{C})$	lo-	10 5.0 12	20 8.0 50	1 1 1	10 5.0 12	20 8.0 50	1 1 1	10 5.0 12	20 8.0 50	-	10 5.0	20 8.0 –	1 1 1	10 5.0	20 8.0 –		mA μA
Output Short Circuit to Ground (Note 8)	I _{SC}	-	40	60	-	40	60	-	40	60	-	40	60	-	40	60	mA
Power Supply Current $ \begin{aligned} &(T_A = T_{high} \text{ to } T_{low}) \\ &(\text{Note 7}) \end{aligned} \\ &V_{CC} = 30 \text{ V} \\ &V_O = 0 \text{ V, } R_L = \infty \end{aligned} \\ &V_{CC} = 5.0 \text{ V,} \\ &V_O = 0 \text{ V, } R_L = \infty \end{aligned} $	I _{CC}		1 1	3.0	-	1.4	3.0	-	-	3.0		-	3.0	-	-	3.0	mA

7. LM224: T_{low} = -25°C, T_{high} = +85°C
LM324/LM324A/LM324E: T_{low} = 0°C, T_{high} = +70°C
LM2902/LM2902E: T_{low} = -40°C, T_{high} = +105°C
LM2902V & NCV2902: T_{low} = -40°C, T_{high} = +125°C
NCV2902 is qualified for automotive use.

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

^{8.} The input common mode voltage or either input signal voltage should not be allowed to go negative by more than 0.3 V. The upper end of the common mode voltage range is V_{CC} –1.7 V, but either or both inputs can go to +32 V without damage, independent of the magnitude

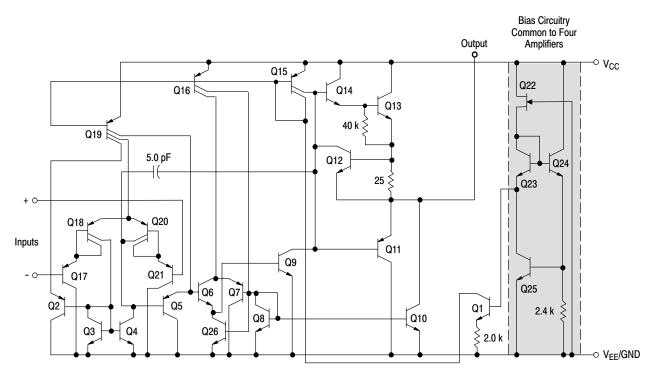


Figure 1. Representative Circuit Diagram (One–Fourth of Circuit Shown)

CIRCUIT DESCRIPTION

The LM324 series is made using four internally compensated, two-stage operational amplifiers. The first stage of each consists of differential input devices Q20 and Q18 with input buffer transistors Q21 and Q17 and the differential to single ended converter Q3 and Q4. The first stage performs not only the first stage gain function but also performs the level shifting and transconductance reduction functions. By reducing the transconductance, a smaller compensation capacitor (only 5.0 pF) can be employed, thus saving chip area. The transconductance reduction is accomplished by splitting the collectors of Q20 and Q18. Another feature of this input stage is that the input common mode range can include the negative supply or ground, in single supply operation, without saturating either the input devices or the differential to single-ended converter. The second stage consists of a standard current source load amplifier stage.

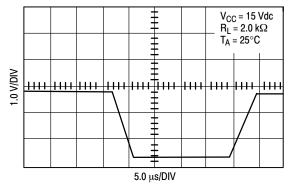
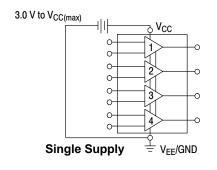


Figure 2. Large Signal Voltage Follower Response

Each amplifier is biased from an internal-voltage regulator which has a low temperature coefficient thus giving each amplifier good temperature characteristics as well as excellent power supply rejection.



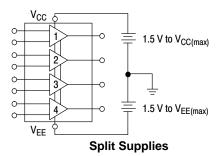


Figure 3.

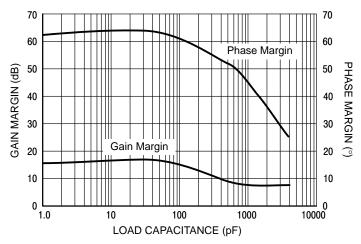


Figure 4. Gain and Phase Margin

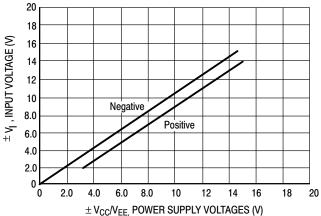


Figure 5. Input Voltage Range

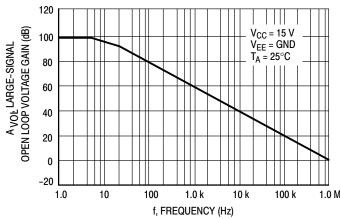


Figure 6. Open Loop Frequency

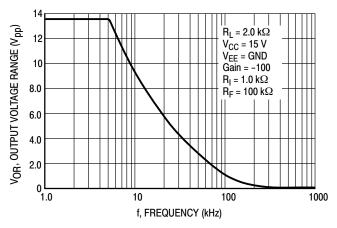


Figure 7. Large-Signal Frequency Response

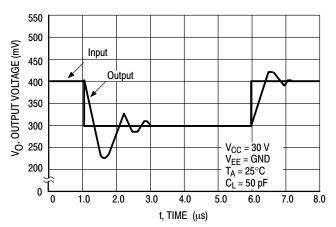


Figure 8. Small-Signal Voltage Follower Pulse Response (Noninverting)

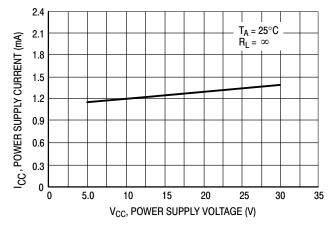


Figure 9. Power Supply Current versus Power Supply Voltage

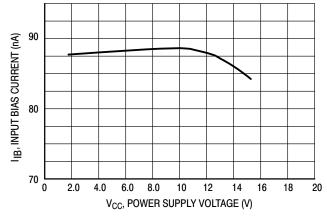


Figure 10. Input Bias Current versus Power Supply Voltage

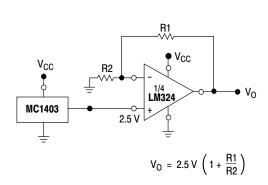


Figure 11. Voltage Reference

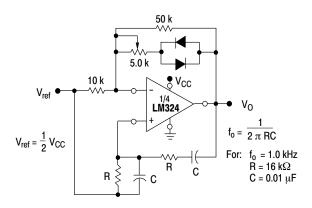


Figure 12. Wien Bridge Oscillator

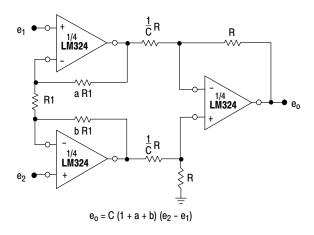


Figure 13. High Impedance Differential Amplifier

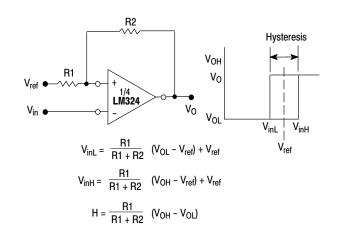


Figure 14. Comparator with Hysteresis

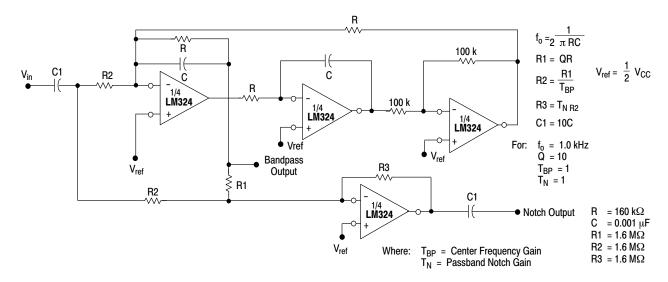


Figure 15. Bi-Quad Filter

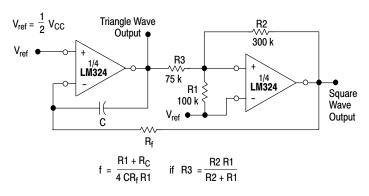


Figure 16. Function Generator

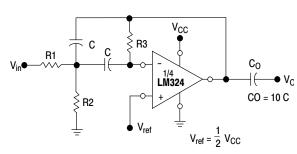


Figure 17. Multiple Feedback Bandpass Filter

Given: f_0 = center frequency

A(f₀) = gain at center frequency

Choose value f₀, C

Then: R3 =
$$\frac{Q}{\pi f_0}$$

$$R1 = \frac{R3}{2 A(f_0)}$$

$$R2 = \frac{R1 R3}{40^2 R1 - R3}$$

For less than 10% error from operational amplifier, $\frac{Q_0 f_0}{BW} < 0.1$

where fo and BW are expressed in Hz.

If source impedance varies, filter may be preceded with voltage follower buffer to stabilize filter parameters.

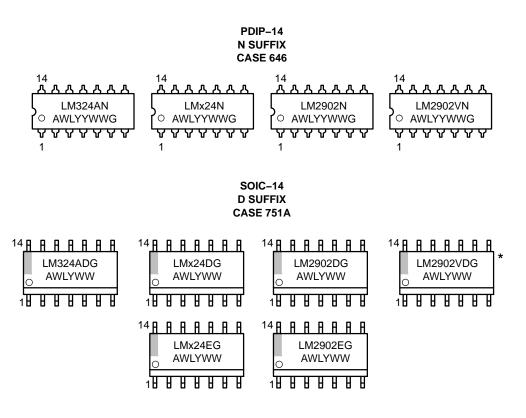
ORDERING INFORMATION

Device	Operating Temperature Range	Package	Shipping [†]
LM224DG		SOIC-14 (Pb-Free)	55 Units/Rail
LM224DR2G	7	SOIC-14 (Pb-Free)	2500/Tape & Reel
LM224DTBG	−25°C to +85°C	TSSOP-14 (Pb-Free)	96 Units/Tube
LM224DTBR2G	7	TSSOP-14 (Pb-Free)	2500/Tape & Reel
LM224NG	7	PDIP-14 (Pb-Free)	25 Units/Rail
LM324DG		SOIC-14 (Pb-Free)	55 Units/Rail
LM324DR2G	7	SOIC-14 (Pb-Free)	2500/Tape & Reel
LM324EDR2G	7	SOIC-14 (Pb-Free)	2500/Tape & Reel
LM324DTBG	7	TSSOP-14 (Pb-Free)	96 Units/Tube
LM324DTBR2G	7	TSSOP-14 (Pb-Free)	2500/Tape & Reel
LM324NG	0°C to +70°C	PDIP-14 (Pb-Free)	25 Units/Rail
LM324ADG		SOIC-14 (Pb-Free)	55 Units/Rail
LM324ADR2G		SOIC-14 (Pb-Free)	2500/Tape & Reel
LM324ADTBG	7	TSSOP-14 (Pb-Free)	96 Units/Tube
LM324ADTBR2G	7	TSSOP-14 (Pb-Free)	2500/Tape & Reel
LM324ANG	7	PDIP-14 (Pb-Free)	25 Units/Rail
LM2902DG		SOIC-14 (Pb-Free)	55 Units/Rail
LM2902DR2G		SOIC-14 (Pb-Free)	2500/Tape & Reel
LM2902EDR2G	4000 to 140500	SOIC-14 (Pb-Free)	2500/Tape & Reel
LM2902DTBG	-40°C to +105°C	TSSOP-14 (Pb-Free)	96 Units/Tube
LM2902DTBR2G	7	TSSOP-14 (Pb-Free)	2500/Tape & Reel
LM2902NG	7	PDIP-14 (Pb-Free)	25 Units/Rail
LM2902VDG		SOIC-14 (Pb-Free)	55 Units/Rail
LM2902VDR2G	7	SOIC-14 (Pb-Free)	2500/Tape & Reel
LM2902VDTBG	7	TSSOP-14 (Pb-Free)	96 Units/Tube
LM2902VDTBR2G	-40°C to +125°C	TSSOP-14 (Pb-Free)	2500/Tape & Reel
LM2902VNG	7	PDIP-14 (Pb-Free)	25 Units/Rail
NCV2902DR2G*	7	SOIC-14 (Pb-Free)	0500Æ 0.B
NCV2902DTBR2G*	7	TSSOP-14 (Pb-Free)	2500/Tape & Reel

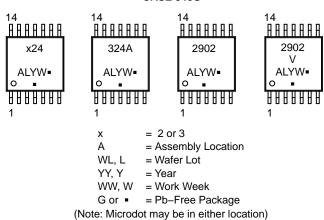
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{*}NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

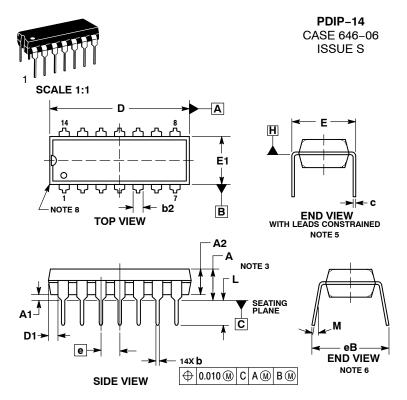
MARKING DIAGRAMS







*This marking diagram also applies to NCV2902.



DATE 22 APR 2015

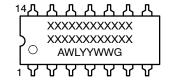
NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: INCHES.
 3. DIMENSIONS A, A1 AND L ARE MEASURED WITH THE PACKAGE SEATED IN JEDEC SEATING PLANE GAUGE GS-3.
 4. DIMENSIONS D, D1 AND E1 DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS. MOLD FLASH OR PROTRUSIONS ARE
- NOT TO EXCEED 0.10 INCH.
 DIMENSION E IS MEASURED AT A POINT 0.015 BELOW DATUM PLANE H WITH THE LEADS CONSTRAINED PERPENDICULAR TO DATUM C.
- DIMENSION 6B IS MEASURED AT THE LEAD TIPS WITH THE LEADS UNCONSTRAINED.
- DATUM PLANE H IS COINCIDENT WITH THE BOTTOM OF THE LEADS, WHERE THE LEADS EXIT THE BODY.

 PACKAGE CONTOUR IS OPTIONAL (ROUNDED OR SQUARE
- CORNERS).

	INC	HES	MILLIM	ETERS
DIM	MIN	MAX	MIN	MAX
Α		0.210		5.33
A1	0.015		0.38	
A2	0.115	0.195	2.92	4.95
b	0.014	0.022	0.35	0.56
b2	0.060	TYP	1.52	TYP
С	0.008	0.014	0.20	0.36
D	0.735	0.775	18.67	19.69
D1	0.005		0.13	
E	0.300	0.325	7.62	8.26
E1	0.240	0.280	6.10	7.11
е	0.100	BSC	2.54	BSC
eB		0.430		10.92
L	0.115	0.150	2.92	3.81
M		10°		10°

GENERIC MARKING DIAGRAM*



XXXXX = Specific Device Code = Assembly Location

WL = Wafer Lot YY = Year WW = Work Week = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

STYLES ON PAGE 2

DOCUMENT NUMBER:	98ASB42428B	Electronic versions are uncontrolled except when accessed directly from Printed versions are uncontrolled except when stamped "CONTROLLED"	
DESCRIPTION:	PDIP-14		PAGE 1 OF 2

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PDIP-14 CASE 646-06 ISSUE S

DATE 22 APR 2015

STYLE 1: PIN 1. COLLECTOR 2. BASE 3. EMITTER 4. NO CONNECTION 5. EMITTER 6. BASE 7. COLLECTOR 8. COLLECTOR 9. BASE 10. EMITTER 11. NO CONNECTION 12. EMITTER 13. BASE 14. COLLECTOR	STYLE 2: CANCELLED	STYLE 3: CANCELLED	STYLE 4: PIN 1. DRAIN 2. SOURCE 3. GATE 4. NO CONNECTION 5. GATE 6. SOURCE 7. DRAIN 8. DRAIN 9. SOURCE 10. GATE 11. NO CONNECTION 12. GATE 13. SOURCE 14. DRAIN
STYLE 5: PIN 1. GATE 2. DRAIN 3. SOURCE 4. NO CONNECTION 5. SOURCE 6. DRAIN 7. GATE 8. GATE 9. DRAIN 10. SOURCE 11. NO CONNECTION 12. SOURCE 13. DRAIN 14. GATE	STYLE 6: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. NO CONNECTION 7. ANODE/CATHODE 8. ANODE/CATHODE 9. ANODE/CATHODE 10. NO CONNECTION 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE	STYLE 7: PIN 1. NO CONNECTION 2. ANODE 3. ANODE 4. NO CONNECTION 5. ANODE 6. NO CONNECTION 7. ANODE 8. ANODE 9. ANODE 10. NO CONNECTION 11. ANODE 12. ANODE 13. NO CONNECTION 14. COMMON CATHODE	STYLE 8: PIN 1. NO CONNECTION 2. CATHODE 3. CATHODE 4. NO CONNECTION 5. CATHODE 6. NO CONNECTION 7. CATHODE 8. CATHODE 9. CATHODE 10. NO CONNECTION 11. CATHODE 12. CATHODE 13. NO CONNECTION 14. COMMON ANODE
STYLE 9: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. ANODE/CATHODE 7. COMMON ANODE 8. COMMON ANODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. NO CONNECTION 12. ANODE/CATHODE 13. ANODE/CATHODE 14. COMMON CATHODE	STYLE 10: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. NO CONNECTION 7. COMMON ANODE 8. COMMON CATHODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE	STYLE 11: PIN 1. CATHODE 2. CATHODE 3. CATHODE 4. CATHODE 5. CATHODE 6. CATHODE 7. CATHODE 8. ANODE 9. ANODE 10. ANODE 11. ANODE 12. ANODE 13. ANODE 14. ANODE	STYLE 12: PIN 1. COMMON CATHODE 2. COMMON ANODE 3. ANODE/CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. COMMON ANODE 7. COMMON CATHODE 8. ANODE/CATHODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. ANODE/CATHODE 12. ANODE/CATHODE 13. ANODE/CATHODE 14. ANODE/CATHODE 14. ANODE/CATHODE

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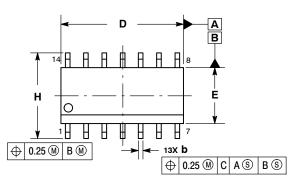
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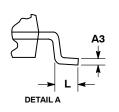


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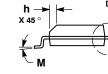
SOIC-14 NB CASE 751A-03 ISSUE L

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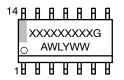




- NOTES:
 1. DIMENSIONING AND TOLERANCING PER
 - ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS.
- DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF AT
- MAXIMUM MATERIAL CONDITION.
 DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSIONS.
- 5. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE

	MILLIN	IETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	1.35	1.75	0.054	0.068
A1	0.10	0.25	0.004	0.010
АЗ	0.19	0.25	0.008	0.010
b	0.35	0.49	0.014	0.019
D	8.55	8.75	0.337	0.344
Е	3.80	4.00	0.150	0.157
е	1.27	BSC	0.050	BSC
Н	5.80	6.20	0.228	0.244
h	0.25	0.50	0.010	0.019
Ĺ	0.40	1.25	0.016	0.049
М	0 °	7°	0 °	7°

GENERIC MARKING DIAGRAM*



XXXXX = Specific Device Code Α = Assembly Location

WL = Wafer Lot Υ = Year WW = Work Week = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator. "G" or microdot " ■". may or may not be present.

SOLDERING FOOTPRINT*

1	14X 1.18
<u> </u>	1.27 PITCH
0.58 J	

DIMENSIONS: MILLIMETERS

STYLES ON PAGE 2

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^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

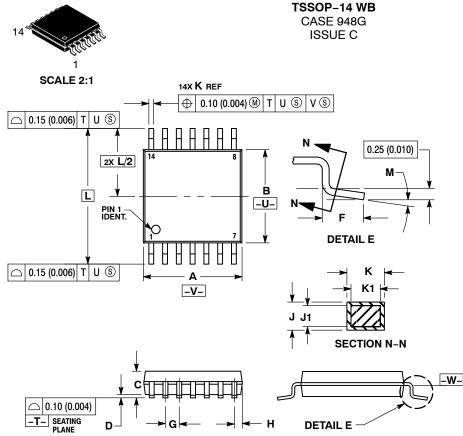
SOIC-14 CASE 751A-03 ISSUE L

DATE 03 FEB 2016

STYLE 1: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. NO CONNECTION 7. ANODE/CATHODE 8. ANODE/CATHODE 9. ANODE/CATHODE 10. NO CONNECTION 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE	STYLE 2: CANCELLED	STYLE 3: PIN 1. NO CONNECTION 2. ANODE 3. ANODE 4. NO CONNECTION 5. ANODE 6. NO CONNECTION 7. ANODE 8. ANODE 9. ANODE 10. NO CONNECTION 11. ANODE 12. ANODE 13. NO CONNECTION 14. COMMON CATHODE	STYLE 4: PIN 1. NO CONNECTION 2. CATHODE 3. CATHODE 4. NO CONNECTION 5. CATHODE 6. NO CONNECTION 7. CATHODE 8. CATHODE 9. CATHODE 10. NO CONNECTION 11. CATHODE 12. CATHODE 13. NO CONNECTION 14. COMMON ANODE
STYLE 5: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. NO CONNECTION 7. COMMON ANODE 8. COMMON CATHODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE	STYLE 6: PIN 1. CATHODE 2. CATHODE 3. CATHODE 4. CATHODE 5. CATHODE 6. CATHODE 7. CATHODE 8. ANODE 9. ANODE 10. ANODE 11. ANODE 12. ANODE 13. ANODE 14. ANODE	STYLE 7: PIN 1. ANODE/CATHODE 2. COMMON ANODE 3. COMMON CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. ANODE/CATHODE 7. ANODE/CATHODE 8. ANODE/CATHODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. COMMON CATHODE 12. COMMON ANODE 13. ANODE/CATHODE 14. ANODE/CATHODE	STYLE 8: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. ANODE/CATHODE 7. COMMON ANODE 8. COMMON ANODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. NO CONNECTION 12. ANODE/CATHODE 13. ANODE/CATHODE 14. COMMON CATHODE

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DATE 17 FEB 2016

- NOTES.

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: MILLIMETER.

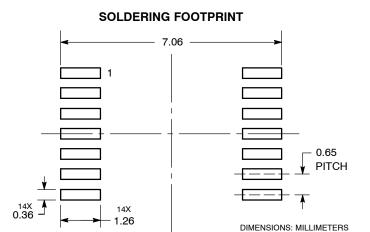
 3. DIMENSION A DOES NOT INCLUDE MOLD
- FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
 DIMENSION B DOES NOT INCLUDE
- INTERLEAD FLASH OR PROTRUSION.
 INTERLEAD FLASH OR PROTRUSION SHALL
- INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.

 5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.

 6. TERMINAL NUMBERS ARE SHOWN FOR DEFERENCE ONLY
- REFERENCE ONLY.
 DIMENSION A AND B ARE TO BE
 DETERMINED AT DATUM PLANE -W-.

	MILLIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	4.90	5.10	0.193	0.200	
В	4.30	4.50	0.169	0.177	
С		1.20		0.047	
D	0.05	0.15	0.002	0.006	
F	0.50	0.75	0.020	0.030	
G	0.65	0.65 BSC		0.026 BSC	
Н	0.50	0.60	0.020	0.024	
J	0.09	0.20	0.004	0.008	
J1	0.09	0.16	0.004	0.006	
K	0.19	0.30	0.007	0.012	
K1	0.19	0.25	0.007	0.010	
L	6.40	6.40 BSC		0.252 BSC	
М	0 °	8 °	o °	a °	

GENERIC MARKING DIAGRAM*





= Assembly Location

= Wafer Lot

= Year W = Work Week

= Pb-Free Package (Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

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